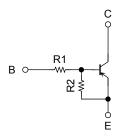
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process) (Bias Resistor Built-in Transistor)

RN2907FE, RN2908FE, RN2909FE

Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications

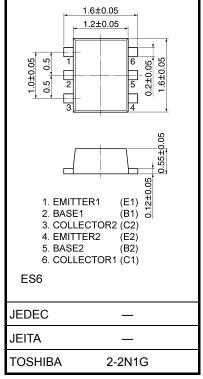
- Two devices are incorporated into an Extreme-Super-Mini (6-pin) package.
- Incorporating a bias resistor into a transistor reduces parts count.
 Reducing the parts count enables the manufacture of ever more compact equipment and lowers assembly cost.
- Complementary to RN1907FE to RN1909FE

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN2907FE	10	47
RN2908FE	22	47
RN2909FE	47	22

Unit: mm

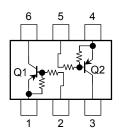


Weight: 0.003 g (typ.)

Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage	RN2907FE	V_{CBO}	-50	V	
Collector-emitter voltage	to 2909FE	V _{CEO}	-50	V	
Emitter-base voltage	RN2907FE		-6	٧	
	RN2908FE	V_{EBO}	-7		
	RN2909FE		-15		
Collector current		IC	-100	mA	
Collector power dissipation	RN2907FE	P _C (Note 1)	100	mW	
Junction temperature	temperature to 2909FE		150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Equivalent Circuit (top view)



Note: Using continuously under heavy loads (e.g. the application of high

temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating

Start of commercial production 2000-05

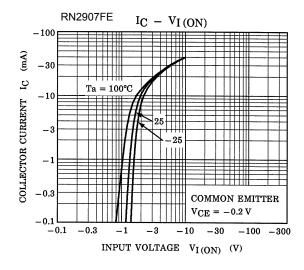


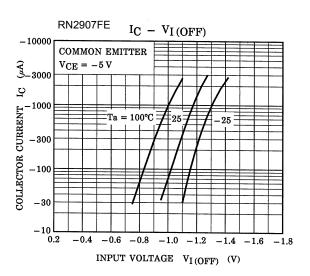
Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

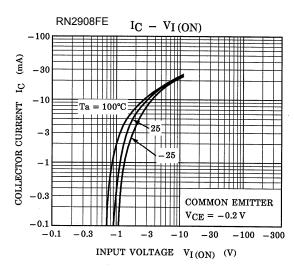
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN2907FE to 2909FE	I _{CBO}	$V_{CB} = -50 \text{ V}, I_E = 0$	_	_	-100	nA
		I _{CEO}	$V_{CE} = -50 \text{ V}, I_B = 0$	_	_	-500	
Emitter cut-off current	RN2907FE	I _{EBO}	$V_{EB} = -6 \text{ V}, I_C = 0$	-0.081	_	-0.15	mA
	RN2908FE		$V_{EB} = -7 \text{ V, } I_{C} = 0$	-0.078	_	-0.145	
	RN2909FE		V _{EB} = -15 V, I _C = 0	-0.167	_	-0.311	
DC current gain	RN2907FE		V _{CE} = -5 V, I _C = -10 mA	80	_	_	
	RN2908FE	h _{FE}		80	_	_	
	RN2909FE			70	_	_	
Collector-emitter saturation voltage	RN2907FE to 2909FE	V _{CE} (sat)	$\begin{split} I_C &= -5 \text{ mA}, \\ I_B &= -0.25 \text{ mA} \end{split}$	_	-0.1	-0.3	V
Input voltage (ON)	RN2907FE	V _I (ON)	$V_{CE} = -0.2 \text{ V},$ $I_{C} = -5 \text{ mA}$	-0.7		-1.8	V
	RN2908FE			-1.0		-2.6	
	RN2909FE			-2.2		-5.8	
Input voltage (OFF)	RN2907FE		V _{CE} = -5 V, I _C = -0.1 mA	-0.5	_	-1.0	V
	RN2908FE	V _{I (OFF)}		-0.6	_	-1.16	
	RN2909FE			-1.5	_	-2.6	
Transition frequency	RN2907FE to 2909FE	f _T	$V_{CE} = -10 \text{ V},$ $I_{C} = -5 \text{ mA}$	_	200	_	MHz
Collector output capacitance	RN2907FE to 2909FE	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0,$ f = 1 MHz	_	3	6	pF
Input resistor	RN2907FE	R1	_	7	10	13	kΩ
	RN2908FE			15.4	22	28.6	
	RN2909FE			32.9	47	61.1	
Resistor ratio	RN2907FE		_	0.191	0.213	0.232	
	RN2908FE	R1/R2		0.421	0.468	0.515	
	RN2909FE			1.92	2.14	2.35	

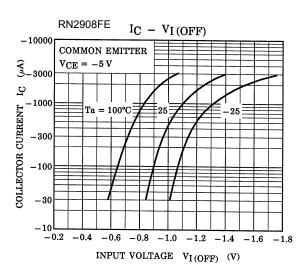
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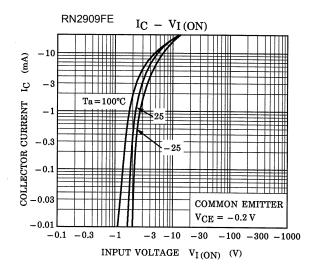
Q1, Q2 Common

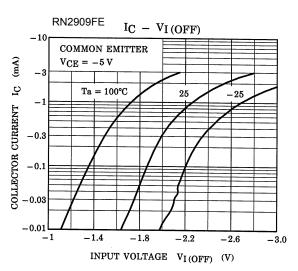




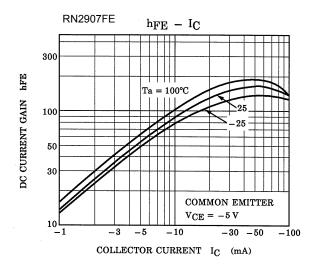


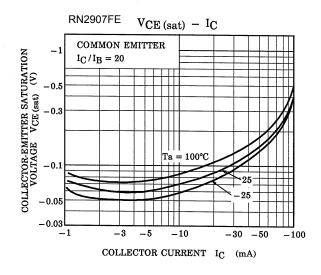


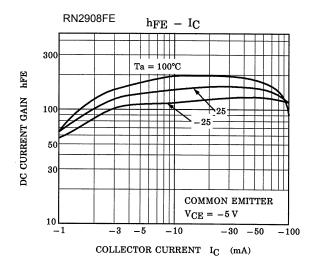


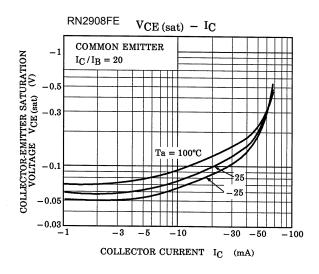


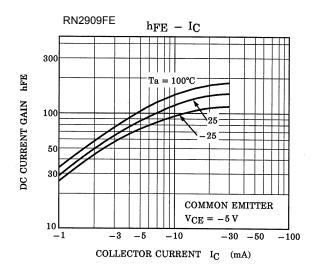
Q1, Q2 Common

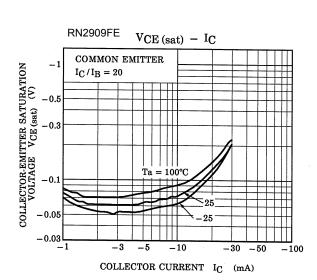


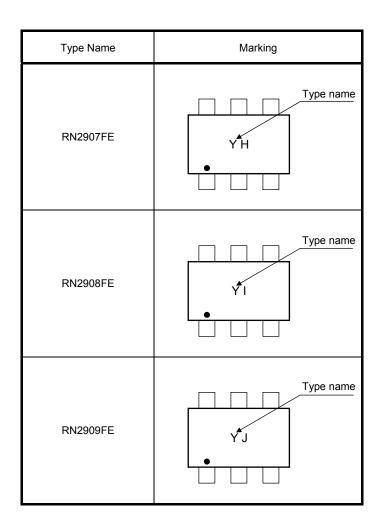












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